TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SG00FU

#### 2 Input NAND Gate

#### **Features**

High-level output current: I<sub>OH</sub>/I<sub>OL</sub> = ±8 mA (min)

at  $V_{CC}$  = 3.0 V

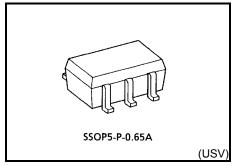
• High-speed operation: t<sub>pd</sub> = 2.5 ns (typ.)

at  $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$ 

• Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V

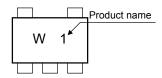
• 5.5-V tolerant inputs.

• 3.6-V power down protection output.

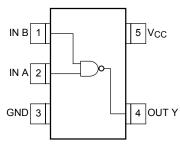


Weight: 0.006 g (typ.)

### Marking



## Pin Assignment (top view)



#### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Value	Unit			
Power supply voltage	Vcc	-0.5~4.6	V			
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V			
DC output voltage	\/	-0.5~ 4.6 (Note 1)	V			
DC output voltage	V <sub>OUT</sub>	-0.5~ V <sub>CC</sub> + 0.5 (Note 2)	V			
Input diode current	I <sub>IK</sub>	-20	mA			
Output diode current	lok	-20 (Note 3)	mA			
DC output current	lout	±25	mA			
DC V <sub>CC</sub> /ground current	Icc	±50	mA			
Power dissipation	P <sub>D</sub>	200	mW			
Storage temperature	T <sub>stg</sub>	-65~150	°C			

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0V$ 

Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: Vout < GND

## **Truth Table**

Α	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

# **IEC Logic Symbol**



## **Operating Ranges**

Characteristics	Symbol	Value	Unit		
Power supply voltage	Vcc	0.9~3.6	V		
Input voltage	V <sub>IN</sub>	0~5.5	V		
Output voltage	Va=	0~3.6 (Note 4)	V		
	Vout	0~V <sub>CC</sub> (Note 5)			
		±8.0 (Note 6)			
	1	±4.0 (Note 7)			
Output Current		±3.0 (Note 8)	mA		
	IOH/IOL	±1.7 (Note 9)			
		±0.3 (Note 10)			
		±0.02 (Note 11)			
Operating temperature	T <sub>opr</sub>	-40~85	°C		
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V		

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 9:  $V_{CC} = 1.4 \sim 1.6 \text{ V}$ 

Note 10:  $V_{CC} = 1.1 \sim 1.3 \text{ V}$ 

Note 11:  $V_{CC} = 0.9 \text{ V}$ 

Note 12:  $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$ 

# **DC Electrical Characteristics**

Characteristics Symbol		Test Condition V <sub>CC</sub> (V)		Ta = 25°C			Ta = -40~85°C		Unit	
				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Onit
					Vcc	_		Vcc	_	\ \ \
High-level VIH input voltage	_		1.1~1.3	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	_		
			1.4~1.6	V <sub>CC</sub> × 0.65		_	V <sub>CC</sub> × 0.65			
			1.65~1.95	V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65			
				2.3~2.7	1.7	_	_	1.7		
				3.0~3.6	2.0	_	_	2.0	_	
				0.9	_	_	GND	_	GND	
			_		_	_	V <sub>CC</sub> × 0.3	_	V <sub>CC</sub> × 0.3	V
Low-level	V <sub>IL</sub>				_	_	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35	
input voltage					_	_	V <sub>CC</sub> × 0.35	_	V <sub>CC</sub> × 0.35	
					_	_	.0.7		0.7	
			3.0~3.6	_	_	8.0		8.0		
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75		V
High-level VOH output voltage			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75		
	V <sub>OH</sub>		$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75		
			$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45		
			$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0	_	_	2.0		
			$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48		_	2.48		
			$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	
Low-level V <sub>OL</sub> output voltage		$I_{OL} = 0.3 \text{ mA}$	1.1~1.3	_		V <sub>CC</sub> × 0.25	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	1	
	V <sub>OL</sub>	$V_{IN} = V_{IH}$	I <sub>OL</sub> = 1.7 mA	1.4~1.6	_		V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	٧
			$I_{OL} = 3.0 \text{ mA}$	1.65~ 1.95	_		0.45	_	0.45	
			$I_{OL} = 4.0 \text{ mA}$	2.3~2.7	_	_	0.4	_	0.4	
			I <sub>OL</sub> = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V		0~3.6		_	±0.1	_	±1.0	μА
Power off leakage current	l <sub>OFF</sub>	V <sub>IN</sub> = 0~5.5V V <sub>OUT</sub> = 0~3.6V		0	_	_	1.0	_	10.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		3.6	_	_	1.0		10.0	μΑ

# AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Onaracteristics			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
		$\begin{array}{c} C_L = 10 \ pF, \\ R_L = 1 \ M\Omega \end{array}$	0.9	_	26.9	_	_	_	
			1.1~1.3	_	10.9	20.7	1.0	38.6	
			1.4~1.6	_	5.9	9.6	1.0	11.3	
			1.65~ 1.95	_	4.5	7.0	1.0	7.5	
			2.3~2.7	_	2.9	4.4	1.0	4.9	
			3.0~3.6	_	2.2	3.5	1.0	4.1	
		$C_L$ = 15 pF, $R_L$ = 1 M $\Omega$	0.9		30.0		_	_	
			1.1~1.3		12.0	24.2	1.0	42.0	ns
	tpLH tpHL		1.4~1.6		6.5	10.5	1.0	12.6	
Propagation delay time			1.65~ 1.95	_	5.0	7.7	1.0	8.0	
			2.3~2.7	_	3.2	4.9	1.0	5.6	
			3.0~3.6		2.5	3.8	1.0	4.4	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		45.0		_		
			1.1~1.3		18.0	33.4	1.0	63.2	
			1.4~1.6		8.9	14.8	1.0	17.9	-
			1.65~ 1.95	_	6.9	10.3	1.0	10.8	
			2.3~2.7	_	4.4	6.4	1.0	6.8	
			3.0~3.6	_	3.5	4.9	1.0	5.4	
Input capacitance	C <sub>IN</sub>	_	3.6	_	3	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 13)	0.9~3.6		6			_	pF

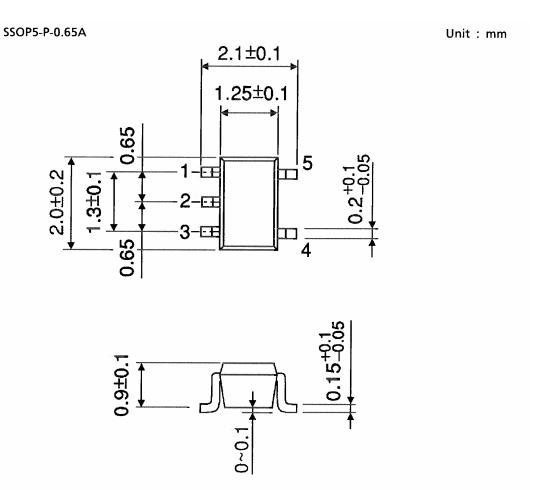
Note 13: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# **Package Dimensions**

**TOSHIBA** 



Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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